## DATA SHEET

## TDA1072AT <br> AM receiver circuit

File under Integrated Circuits, IC01

## GENERAL DESCRIPTION

The TDA 1072AT integrated AM receiver circuit performs the active and part of the filtering functions of an AM radio receiver. It is intended for use in mains-fed home receivers and car radios. The circuit can be used for oscillator frequencies up to 50 MHz and can handle RF signals up to 500 mV . RF radiation and sensitivity to interference are minimized by an almost symmetrical design. The voltage-controlled oscillator provides signals with extremely low distortion and high spectral purity over the whole frequency range even when tuning with variable capacitance diodes. If required, band switching diodes can easily be applied. Selectivity is obtained using a block filter before the IF amplifier.

## Features

- Inputs protected against damage by static discharge
- Gain-controlled RF stage
- Double balanced mixer
- Separately buffered, voltage-controlled and temperature-compensated oscillator, designed for simple coils
- Gain-controlled IF stage with wide AGC range
- Full-wave, balanced envelope detector
- Internal generation of AGC voltage with possibility of second-order filtering
- Buffered field strength indicator driver with short-circuit protection
- AF preamplifier with possibilities for simple AF filtering
- Electronic standby switch.


## QUICK REFERENCE DATA

| PARAMETER | CONDITIONS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage range |  | $V_{P}$ | 7.5 | - | 10 | V |
| Supply current range |  | $\mathrm{I}_{\mathrm{P}}$ | 15 | - | 26 | mA |
| RF input voltage for $\mathrm{S}+\mathrm{N} / \mathrm{N}=6 \mathrm{~dB} \text { at } \mathrm{m}=30 \%$ |  | $V_{1}$ | - | 1.5 | - | $\mu \mathrm{V}$ |
| RF input voltage for $3 \%$ total harmonic distortion (THD) at $m=80 \%$ |  | $V_{1}$ | - | $500$ | - | mV |
| AF output voltage with $\begin{aligned} & V_{\mathrm{I}}=2 \mathrm{mV} ; \mathrm{f}_{\mathrm{l}}=1 \mathrm{MHz} ; \\ & \mathrm{m}=30 \% \text { and } \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz} \end{aligned}$ |  | $V_{\mathrm{O}(\mathrm{AF})}$ | - | 310 | - | mV |
| AGC range: change of $V_{\text {I }}$ for 1 dB change of $\mathrm{V}_{\mathrm{O}(\mathrm{AF})}$ |  |  | - | $86$ | - | dB |
| Field strength indicator voltage at $\mathrm{V}_{\mathrm{I}}=500 \mathrm{mV}$; $R_{\mathrm{L}(9)}=2.7 \mathrm{k} \Omega$ |  | $\mathrm{V}_{\mathrm{IND}}$ | - | $2.8$ | - | V |

## PACKAGE OUTLINE

16-lead mini-pack; plastic (SO16; SOT109A); SOT109-1; 1996 August 13.

(1) Coil data: TOKO sample no. 7XNS-A7523DY; L1: N1/N2 $=12 / 32 ; Q_{0}=65 ; Q_{B}=57$.

Filter data: $Z_{F}=700 \Omega$ at $R_{3-4}=3 \mathrm{k} \Omega ; Z_{1}=4.8 \mathrm{k} \Omega$.
Fig. 1 Block diagram and test circuit (connections shown in broken lines are not part of the test circuit).

## FUNCTIONAL DESCRIPTION

## Gain-controlled RF stage and mixer

The differential amplifier in the RF stage employs an AGC negative feedback network to provide a wide dynamic range. Very good cross-modulation behaviour is achieved by AGC delays at the various signal stages. Large signals are handled with low distortion and the $\mathrm{S} / \mathrm{N}$ ratio of small signals is also improved. Low noise working is achieved in the differential amplifier by using transistors with a low base resistance.

A double balanced mixer provides the IF output to pin 1.

## Oscillator

The differential amplifier oscillator is temperature compensated and is suitable for simple coil connection. The oscillator is voltage-controlled and has little distortion or spurious radiation. It is specially suitable for electronic tuning using variable capacitance diodes. Band switching diodes can easily be applied using the stabilized voltage $\mathrm{V}_{11-16}$. An extra buffered oscillator output is available for driving a synthesizer. If this is not needed, resistor $\mathrm{R}_{\mathrm{L}(10)}$ can be omitted.

## Gain-controlled IF amplifier

This amplifier comprises two cascaded, variable-gain differential amplifier stages coupled by a band-pass filter. Both stages are gain-controlled by the AGC negative feedback network.

## Detector

The full-wave, balanced envelope detector has very low distortion over a wide dynamic range. The residual IF carrier is blocked from the signal path by an internal low-pass filter.

## AF preamplifier

This stage preamplifies the audio frequency output. The amplifier output stage uses an emitter follower with a series resistor which, together with an external capacitor, provides the required low-pass filtering for AF signals.

## AGC amplifier

The AGC amplifier provides a control voltage which is proportional to the carrier amplitude. Second-order filtering of the AGC voltage achieves signals with very little distortion, even at low audio frequencies. This method of filtering also gives a fast AGC settling time which is advantageous for electronic search tuning. The AGC settling time can be further reduced by using capacitors of smaller value in the external filter. The AGC voltage is fed to the RF and IF stages via suitable AGC delays. The capacitor at pin 7 can be omitted for low-cost applications.

## Field strength indicator output

A buffered voltage source provides a high-level field strength output signal which has good linearity for logarithmic input signals over the whole dynamic range. If field strength information is not needed, $\mathrm{R}_{\mathrm{L}(9)}$ can be omitted.

## Standby switch

This switch is primarily intended for AM/FM band switching. During standby mode the oscillator, mixer and demodulator are switched off.

## Short-circuit protection

All pins have short-circuit protection to ground.

## RATINGS

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

| PARAMETER | CONDITIONS | SYMBOL | MIN. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{P}}=\mathrm{V}_{13-16}$ | $\mathrm{V}_{13}$ | - | 12 | V |
| Input voltage |  |  |  |  |  |
| pins 14-15 |  | $\mathrm{V}_{14-15}$ | - | 10 | V |
| pins 14-16 |  | $V_{14-16}$ | - | $V_{P}$ | V |
| pins 15-16 |  | $\mathrm{V}_{15-16}$ | - | $V_{P}$ | V |
| pins 14-16 |  | $V_{14-16}$ | - | -0.6 | V |
| pins 15-16 |  | $\mathrm{V}_{15-16}$ | - | -0.6 | V |
| Input current |  |  |  |  |  |
| (pins 14 and 15) |  | $\mathrm{l}_{14-15}$ | - | 200 | mA |
| Total power dissipation (note 1) |  | $\mathrm{P}_{\text {tot }}$ | - | 300 | mW |
| Operating ambient temperature range |  | $\mathrm{T}_{\text {amb }}$ | -40 | + 80 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $\mathrm{T}_{\text {stg }}$ | -55 | + 150 | ${ }^{\circ} \mathrm{C}$ |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | - | + 125 | ${ }^{\circ} \mathrm{C}$ |

## Note

1. Mounted on epoxiprint.

## THERMAL RESISTANCE

From junction to ambient
$\mathrm{R}_{\mathrm{th} \mathrm{j}-\mathrm{a}}$
300 K/W
160 K/W ${ }^{(1)}$

## Note

1. Mounted on epoxiprint.

## CHARACTERISTICS

$\mathrm{V}_{\mathrm{P}}=\mathrm{V}_{13-16}=8.5 \mathrm{~V} ; \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C} ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz} ; \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz} ; \mathrm{m}=30 \% ; \mathrm{f}_{\mathrm{IF}}=460 \mathrm{kHz}$; measured in test circuit of Fig. 1 ; all measurements are with respect to ground (pin 16); unless otherwise specified

| PARAMETER | CONDITIONS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supplies |  |  |  |  |  |  |
| Supply voltage (pin 13) |  | $\mathrm{V}_{13}$ | 7.5 | 8.5 | 10 | V |
| Supply current (pin 13) |  | $\mathrm{I}_{13}$ | 15 | 23 | 27 | mA |
| RF stage and mixer |  |  |  |  |  |  |
| Input voltage (DC value) |  | $\mathrm{V}_{14-15}$ | - | $\mathrm{V}_{\mathrm{P}} / 2$ | - | V |
| RF input impedance at |  |  |  |  |  |  |
| $\mathrm{V}_{1}<300 \mu \mathrm{~V}$ |  | $\mathrm{R}_{14-15}$ | - | 5.5 | - | $\mathrm{k} \Omega$ |
|  |  | $\mathrm{C}_{14-15}$ | - | 25 | - | pF |
| RF input impedance at |  |  |  |  |  |  |
| $V_{1}>10 \mathrm{mV}$ |  | $\mathrm{R}_{14-15}$ | - | 8 | - | $\mathrm{k} \Omega$ |
|  |  | $\mathrm{C}_{14-15}$ | - | 22 | - | pF |
| IF output impedance |  | $\mathrm{R}_{1}$ | 500 | 0 | 0 | $\mathrm{k} \Omega$ |
|  |  | $\mathrm{C}_{1}$ | - | 6 | - | pF |
| Conversion transconductance before start of AGC |  |  |  |  |  |  |
| Maximum IF output voltage, inductive coupling to pin 1, |  |  |  |  |  |  |
| (peak-to-peak value) |  | $V_{1(p-p)}$ | - | 5 | - | V |
| DC value of output current |  |  |  |  |  |  |
| AGC range of input stage |  | 1 | - | $\left\lvert\, \begin{aligned} & 1.2 \\ & 30 \end{aligned}\right.$ | - | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~dB} \end{aligned}$ |
| RF signal handling capability: |  |  |  |  |  |  |
| input voltage for THD $=3 \%$ at $m=80 \%$ (RMS value) |  | $\mathrm{V}_{1(\mathrm{rms})}$ | - | 500 | - | mV |
| Oscillator |  |  |  |  |  |  |
| Frequency range |  | $\Delta \mathrm{f}$ | 0.6 | - | 60 | MHz |
| Oscillator amplitude (pins 11 to 12) |  |  |  |  |  |  |
| (peak-to-peak value) |  | $\mathrm{V}_{11-12(\mathrm{p}-\mathrm{p})}$ | - | 130 | 150 | mV |
| External load impedance |  | $\mathrm{R}_{11-12(\mathrm{ext})}$ | 0.5 | - | 200 | $\mathrm{k} \Omega$ |
| External load impedance for no oscillation |  | $\mathrm{R}_{11-12(\mathrm{ext})}$ | - | - | 60 | $\Omega$ |
| Ripple rejection at $V_{P}$ $=100 \mathrm{mV}$ (RMS value); |  |  |  |  |  |  |
| $=100 \mathrm{mV}$ (RMS value); |  |  |  |  |  |  |
| $\begin{aligned} & \mathrm{f}_{\mathrm{p}}=100 \mathrm{~Hz} \\ & \left(\mathrm{RR}=20 \log \left[\mathrm{~V}_{13} / \mathrm{V}_{11}\right]\right) \end{aligned}$ |  |  |  |  |  |  |



| PARAMETER | CONDITIONS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Standby switch |  |  |  |  |  |  |
| Switching threshold at |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{P}}=7.5$ to 18 V ; |  |  |  |  |  |  |
| $\mathrm{T}_{\text {amb }}=-40$ to $+80^{\circ} \mathrm{C}$ |  |  |  |  |  |  |
| ON-voltage |  | $\mathrm{V}_{2}$ | 0 | - | 2 | V |
| OFF-voltage |  | $\mathrm{V}_{2}$ | 3.5 | - | 20 | V |
| ON-current | $\mathrm{V}_{2}=0 \mathrm{~V}$ | $\mathrm{I}_{2}$ | - | - | -200 | $\mu \mathrm{A}$ |
| OFF-current | $\mathrm{V}_{2}=20 \mathrm{~V}$ | $\mathrm{I}_{2}$ | - | - | 10 | $\mu \mathrm{A}$ |

## OPERATING CHARACTERISTICS

$\mathrm{V}_{\mathrm{P}}=8.5 \mathrm{~V} ; \mathrm{f}_{\mathrm{l}}=1 \mathrm{MHz} ; \mathrm{m}=30 \% ; \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz} ; \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$; measured in Fig. 1 ; unless otherwise specified

| PARAMETER | CONDITIONS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RF sensitivity |  |  |  |  |  |  |
| RF input required for |  |  |  |  |  |  |
| $\mathrm{S}+\mathrm{N} / \mathrm{N}=6 \mathrm{~dB}$ |  | $V_{1}$ | - | 1.5 | - | $\mu \mathrm{V}$ |
| $\mathrm{S}+\mathrm{N} / \mathrm{N}=26 \mathrm{~dB}$ |  | $V_{1}$ | - | 15 | - | $\mu \mathrm{V}$ |
| $\mathrm{S}+\mathrm{N} / \mathrm{N}=46 \mathrm{~dB}$ |  | $V_{1}$ | - | 150 | - | $\mu \mathrm{V}$ |
| RF input at start of AGC |  | $V_{1}$ | - | 30 | - | $\mu \mathrm{V}$ |
| RF large signal handling |  |  |  |  |  |  |
| RF input at |  |  |  |  |  |  |
| THD $=3 \% ; m=80 \%$ |  | $V_{1}$ | - | 500 | - | mV |
| THD $=3 \% ; m=30 \%$ |  | $V_{1}$ | - | 700 | - | mV |
| THD $=10 \% ; m=30 \%$ |  | $V_{1}$ | - | 900 | - | mV |
| AGC range |  |  |  |  |  |  |
| Change of $\mathrm{V}_{1}$ for |  |  |  |  |  |  |
| 1 dB change of $\mathrm{V}_{\mathrm{O}(\mathrm{AF})}$ | $V_{1(\text { ref })}=500 \mathrm{mV}$ | $\Delta \mathrm{V}_{1}$ | - | 86 | - | dB |
| 6 dB change of $\mathrm{V}_{\mathrm{O}(\mathrm{AF})}$ | $V_{1(\text { ref })}=500 \mathrm{mV}$ | $\Delta \mathrm{V}_{1}$ | - | 91 | - | dB |
| Output signal |  |  |  |  |  |  |
| AF output voltage at |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{I}}=4 \mu \mathrm{~V}$ | $m=80 \%$ | $\mathrm{V}_{\text {O(AF) }}$ | - | 130 | - | mV |
| $V_{1}=1 \mathrm{mV}$ |  | $\mathrm{V}_{\text {O(AF) }}$ | 240 | 310 | 390 | mV |
| Total harmonic distortion at |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{I}}=1 \mathrm{mV}$ | $m=80 \%$ | $\mathrm{d}_{\text {tot }}$ | - | 0.5 | - | \% |
| $\mathrm{V}_{1}=500 \mathrm{mV}$ | $\mathrm{m}=30 \%$ | $\mathrm{d}_{\text {tot }}$ | - | 1 | - | \% |
| Signal-to-noise ratio | $\mathrm{V}_{1}=100 \mathrm{mV}$ | S+N/N | - | 58 | - | dB |


| PARAMETER | CONDITIONS | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ripple rejection at $\begin{aligned} & V_{I}=2 \mathrm{mV} \\ & \mathrm{~V}_{\mathrm{P}}=100 \mathrm{mV}(\mathrm{RMS} \text { value }) \\ & \mathrm{f}_{\mathrm{p}}=100 \mathrm{~Hz} \\ & \left(\mathrm{RR}=20 \log \left[\mathrm{~V}_{\mathrm{P}} / \mathrm{V}_{\mathrm{O}(\mathrm{AF})}\right]\right) \end{aligned}$ <br> Unwanted signals <br> Suppression of IF whistles at $\mathrm{V}_{\mathrm{I}}=15 \mu \mathrm{~V}$; $\mathrm{m}=0 \%$ related to AF signal of $m=30 \%$ <br> at $f_{I} \approx 2 \times f_{I F}$ <br> at $\mathrm{f}_{\mathrm{I}} \approx 3 \times \mathrm{f}_{\mathrm{IF}}$ <br> IF suppression at RF input <br> for symmetrical input <br> for asymmetrical input <br> Residual oscillator signal at mixer output at $f_{\text {osc }}$ <br> at $2 \times \mathrm{f}_{\text {osc }}$ |  | RR <br> $\alpha_{2 I F}$ <br> $\alpha_{3 I F}$ <br> $\alpha_{\text {IF }}$ <br> $\alpha_{\text {IF }}$ <br> $I_{(0 s c)}$ <br> $I_{(20 s c)}$ |  | 38 <br> 37 <br> 44 <br> 40 <br> 40 <br> 1 <br> 1.1 |  | dB <br> dB <br> dB <br> dB <br> dB <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |

## APPLICATION INFORMATION


7287701.1
(1) Capacitor values depend on crystal type.
(2) Coil data: 9 windings of 0.1 mm dia laminated Cu wire on TOKO coil set 7 K 199 CN ; $\mathrm{Q}_{0}=80$.

Fig. 2 Oscillator circuit using quartz crystal; centre frequency $=27 \mathrm{MHz}$.


Fig. 3 AF output as a function of RF input in the circuit of Fig. $1 ; \mathrm{f}_{\mathrm{l}}=1 \mathrm{MHz} ; \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz}$; $m=30 \%$.


Fig. 4 Total harmonic distortion and $\mathrm{S}+\mathrm{N} / \mathrm{N}$ as functions of RF input in the circuit of Fig.1; $\mathrm{m}=30 \%$ for $(\mathrm{S}+\mathrm{N}) / \mathrm{N}$ curve and $\mathrm{m}=80 \%$ for THD curve.


Fig. 5 Total harmonic distortion as a function of modulation frequency at $\mathrm{V}_{\mathrm{I}}=5 \mathrm{mV} ; \mathrm{m}=80 \%$; measured in the circuit of Fig. 1 with $\mathrm{C}_{7-16 \text { (ext) }}=0 \mu \mathrm{~F}$ and $2.2 \mu \mathrm{~F}$.



Fig. 8 Car radio application with inductive tuning.


Fig. 9 AF output as a function of RF input using the circuit of Fig. 8 with that of Fig.1.


Fig. 10 Suppression of cross-modulation as a function of input signal, measured in the circuit of Fig. 8 with the input circuit as shown in Fig.11. Curve is for wanted $\mathrm{V}_{\mathrm{O}(\mathrm{AF})} /$ unwanted $\mathrm{V}_{\mathrm{O}(\mathrm{AF})}=20 \mathrm{~dB} ; \mathrm{V}_{\text {rff }}, \mathrm{V}_{\text {rfu }}$ are signals at the aerial input, $\mathrm{V}^{\prime}{ }^{\text {aew }}, \mathrm{V}^{\prime}$ aeu are signals at the unloaded output of the aerial.
Wanted signal ( $\left.V^{\prime}{ }^{\prime}{ }^{\prime e w}, V_{\text {rfw }}\right): f_{i}=1 \mathrm{MHz} ; \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz} ; \mathrm{m}=30 \%$.
Unwanted signal ( $\mathrm{V}^{\prime}{ }_{\text {aeu }}, \mathrm{V}_{\text {rfu }}$ ) $\mathrm{f}_{\mathrm{i}}=900 \mathrm{kHz} ; \mathrm{f}_{\mathrm{m}}=400 \mathrm{~Hz} ; \mathrm{m}=30 \%$.
Effective selectivity of input tuned circuit $=21 \mathrm{~dB}$.


Fig. 11 Input circuit to show cross-modulation suppression (see Fig.10).


Fig. 12 Oscillator amplitude as a function of the impedance at pins 11 and 12 in the circuit of Fig.8.


Fig. 13 Total harmonic distortion and $(\mathrm{S}+\mathrm{N}) / \mathrm{N}$ as functions of RF input using the circuit of Fig. 8 with that of Fig.1.


Fig. 14 Forward transfer impedance as a function of intermediate frequency for filters 1 to 4 shown in Fig.14; centre frequency $=455 \mathrm{kHz}$.


Fig. 15 IF filter variants applied to the circuit of Fig.1; for filter data refer to Table 1.

\begin{tabular}{|c|c|c|c|c|c|c|}
\hline FILTER NO. \& 1 \& 2 \& \multicolumn{2}{|l|}{3} \& 4 \& UNIT \\
\hline \begin{tabular}{l}
Coil data \\
Value of C \\
N1: N2 \\
Diameter of Cu \\
\(Q_{0}\) \\
of laminated wire \\
Schematic * \\
windings \\
Toko order no.
\end{tabular} \& \[
\begin{aligned}
\& \text { L1 } \\
\& 3900 \\
\& 12: 32 \\
\& \\
\& 0.09 \\
\& 65 \text { (typ.) } \\
\& \\
\& \\
\& \\
\& \\
\& \\
\& \text { 7XNS-A7523DY }
\end{aligned}
\] \& \[
\begin{aligned}
\& \text { L1 } \\
\& 430 \\
\& 13:(33+66) \\
\& 0.08 \\
\& 50 \\
\& \\
\& \\
\& \\
\& \text { L7PES-A0060BTG }
\end{aligned}
\] \& \[
\begin{aligned}
\& \hline \text { L1 } \\
\& 3900 \\
\& 15: 31 \\
\& \\
\& 0.09 \\
\& 75 \\
\& \\
\& \\
\& \\
\& \\
\& \text { 7XNS-A7518DY }
\end{aligned}
\] \& \begin{tabular}{|ll}
\hline L2 \\
4700 \\
\(29: 29\) \& \\
\& \\
0.08 \\
60 \& \\
\& \\
\& \\
\& \\
(N1) \& (N2) \\
7XNS-A7521AIH
\end{tabular} \&  \& pF

mm <br>

\hline | Resonators |
| :--- |
| Murata type |
| D (typical value) |
| $R_{G}, R_{L}$ |
| Bandwidth ( -3 dB ) |
| $\mathrm{S}_{9 k H z}$ | \& \[

$$
\begin{aligned}
& \text { SFZ455A } \\
& 4 \\
& 3 \\
& 4.2 \\
& 24
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \text { SFZ455A } \\
& 4 \\
& 3 \\
& 4.2 \\
& 24
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \text { SFZ45: } \\
& 4 \\
& 3 \\
& 4.2 \\
& 24
\end{aligned}
$$

\] \& \& \[

$$
\begin{array}{|l}
\text { SFT455B } \\
6 \\
3 \\
4.5 \\
38
\end{array}
$$

\] \& \[

$$
\begin{gathered}
\mathrm{dB} \\
\mathrm{k} \Omega \\
\mathrm{kHz} \\
\mathrm{~dB}
\end{gathered}
$$
\] <br>

\hline | Filter data |
| :--- |
| $Z_{1}$ |
| $Q_{B}$ |
| $Z_{F}$ |
| Bandwidth (-3 dB) |
| $\mathrm{S}_{9 \mathrm{kHz}}$ |
| $\mathrm{S}_{18 \mathrm{kHz}}$ |
| $\mathrm{S}_{27 \mathrm{kHz}}$ | \& \[

$$
\begin{aligned}
& 4.8 \\
& 57 \\
& 0.70 \\
& 3.6 \\
& 35 \\
& 52 \\
& 63
\end{aligned}
$$
\] \& 3.8

40
0.67
3.8
31
49

58 \& |  | 4.2 |
| :--- | :--- |
| 52 (L1) |  |
|  | 0.68 |
| 3.6 |  |
|  | 36 |
|  | 54 |
|  | 66 | \& 18 (L2) \& \[

$$
\begin{array}{|l}
4.8 \\
55 \\
0.68 \\
4.0 \\
42 \\
64 \\
74 \\
\hline
\end{array}
$$
\] \& $k \Omega$

$\mathrm{k} \Omega$
kHz
dB
dB
dB <br>
\hline
\end{tabular}

* The beginning of an arrow indicates the beginning of a winding; N 1 is always the inner winding. N 2 the outer winding.


## PACKAGE OUTLINE

SO16: plastic small outline package; 16 leads; body width 3.9 mm
SOT109-1

detail X


DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | $\begin{gathered} \mathrm{A} \\ \max . \end{gathered}$ | $\mathrm{A}_{1}$ | $\mathrm{A}_{2}$ | $\mathrm{A}_{3}$ | $\mathrm{b}_{\mathrm{p}}$ | c | $D^{(1)}$ | $E^{(1)}$ | e | $\mathrm{H}_{\mathrm{E}}$ | L | $L_{p}$ | Q | v | w | y | $\mathrm{Z}^{(1)}$ | $\theta$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.75 | $\begin{aligned} & 0.25 \\ & 0.10 \end{aligned}$ | $\begin{aligned} & 1.45 \\ & 1.25 \end{aligned}$ | 0.25 | $\begin{aligned} & 0.49 \\ & 0.36 \end{aligned}$ | $\begin{aligned} & 0.25 \\ & 0.19 \end{aligned}$ | $\begin{gathered} 10.0 \\ 9.8 \end{gathered}$ | $\begin{aligned} & 4.0 \\ & 3.8 \end{aligned}$ | 1.27 | $\begin{aligned} & 6.2 \\ & 5.8 \end{aligned}$ | 1.05 | $\begin{aligned} & 1.0 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & 0.7 \\ & 0.6 \end{aligned}$ | 0.25 | 0.25 | 0.1 | $\begin{aligned} & 0.7 \\ & 0.3 \end{aligned}$ | $\begin{aligned} & 8^{\circ} \\ & 0^{\circ} \end{aligned}$ |
| inches | 0.069 | $\begin{array}{\|l\|} \hline 0.0098 \\ 0.0039 \end{array}$ | $\begin{aligned} & 0.057 \\ & 0.049 \end{aligned}$ | 0.01 | $\begin{aligned} & 0.019 \\ & 0.014 \end{aligned}$ | $\begin{array}{\|l\|} \hline 0.0098 \\ 0.0075 \\ \hline \end{array}$ | $\begin{aligned} & 0.39 \\ & 0.38 \end{aligned}$ | $\begin{aligned} & 0.16 \\ & 0.15 \end{aligned}$ | 0.050 | $\begin{aligned} & 0.24 \\ & 0.23 \end{aligned}$ | 0.041 | $\begin{aligned} & 0.039 \\ & 0.016 \end{aligned}$ | $\begin{aligned} & 0.028 \\ & 0.020 \end{aligned}$ | 0.01 | 0.01 | 0.004 | $\begin{aligned} & 0.028 \\ & 0.012 \end{aligned}$ |  |

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES |  |  | EUROPEAN PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | EIAJ |  |  |
| SOT109-1 | 076E07S | MS-012AC |  | $\square$ + | $\begin{aligned} & -91-08-13 \\ & 95-01-23 \end{aligned}$ |

## SOLDERING

## Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398652 90011).

## Reflow soldering

Reflow soldering techniques are suitable for all SO packages.
Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.
Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to $250^{\circ} \mathrm{C}$.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at $45^{\circ} \mathrm{C}$.

## Wave soldering

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is $260^{\circ} \mathrm{C}$, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than $150^{\circ} \mathrm{C}$ within 6 seconds. Typical dwell time is 4 seconds at $250^{\circ} \mathrm{C}$.
A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

## Repairing soldered joints

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V ) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300^{\circ} \mathrm{C}$. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and $320^{\circ} \mathrm{C}$.

## DEFINITIONS

| Data sheet status |  |
| :--- | :--- |
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or <br> more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation <br> of the device at these or at any other conditions above those given in the Characteristics sections of the specification <br> is not implied. Exposure to limiting values for extended periods may affect device reliability. |

## Application information

Where application information is given, it is advisory and does not form part of the specification.

## LIFE SUPPORT APPLICATIONS

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